

2SC3649S-TD-E

2SC3649S-TD-E Information

www.interner.co		2SC3649S-TD-E ON Semiconductor Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single TRANS NPN 160V 1.5A SOT89-3 TO-243AA For the pricing/inventory/lead time, please contact us	
For Reference Or	nly	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2SC3649S-TD-E Specifications

Manufacturer Part Number	2SC3649S-TD-E	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single	
Package	TO-243AA	
Series	-	
Transistor Type	NPN	
Current - Collector (Ic) (Max)	1.5A	
Voltage - Collector Emitter Breakdown (Max)	160V	
Vce Saturation (Max) @ Ib, Ic	450mV @ 50mA, 500mA	
Current - Collector Cutoff (Max)	1μA (ICBO)	
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 100mA, 5V	
Power - Max	500mW	
Frequency - Transition	120MHz	
Operating Temperature	150°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	TO-243AA	
Supplier Device Package	PCP	
	Report errors?	

2SC3649S-TD-E Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

2SC3649S-TD-E Payment Methods



If you have any question about 2SC3649S-TD-E, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com